



## Nitride Semiconductor Devices and Applications

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Deadline for manuscript submissions:

**closed (31 May 2024)**

### Message from the Guest Editors

This Special Issue on “Nitride Semiconductor Devices and Applications” focuses on nitride semiconductor growth and characterization, nitride semiconductor devices, and their application circuits. The main goal of Special Issue is to highlight new scientific knowledge relevant, but not limited, to:

- Nitride semiconductor epitaxy growth and characterization;
- Nitride semiconductor devices: RF/power/LED/LD, etc.;
- RF application circuits: PA, LNA, Switch, etc.;
- Power IC: DC/DC converter, inverter, driver, etc.





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## Editor-in-Chief

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## Message from the Editor-in-Chief

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